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Atty. Dkt. No. 039153-0688

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Ihsan J. DJOMEHRI

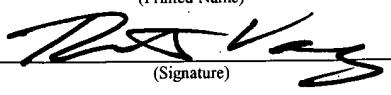
Title: STRAINED SILICON MOSFETS
HAVING NMOS GATES WITH
WORK FUNCTIONS FOR
COMPENSATING NMOS
THRESHOLD VOLTAGE SHIFT

Appl. No.: 10/738,496

Filing Date: 12/17/2003

Examiner: V. Hung

Art Unit: 2811

CERTIFICATE OF EXPRESS MAILING	
I hereby certify that this correspondence is being deposited with the United States Postal Service's "Express Mail Post Office To Addressee" service under 37 C.F.R. § 1.10 on the date indicated below and is addressed to: Mail Stop Amendment, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.	
EV 445626073 US (Express Mail Label Number)	December 14, 2004 (Date of Deposit)
Ruthie Vallejo (Printed Name)	
 (Signature)	

RESPONSE TO ELECTION REQUIREMENT

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In response to the restriction requirement set forth in the Office Action mailed December 3, 2004, Applicant hereby provisionally elects Embodiment 1 of Figures 5a-5f. Claims 9-12 read on this embodiment. Applicant reserves the right to file a divisional application on the non-elected claims.

Respectfully submitted,

Date 14 December 2004

By Ronald Coslick

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